

Metal-Oxide-Semiconductor (MOS) Memory Market Forecast to Reach \$96.36 Billion by 2030 with a 10.8% CAGR

The Business Research Company's Metal-Oxide-Semiconductor (MOS) Memory Global Market Report 2026 – Market Size, Trends, And Forecast 2026-2035

LONDON, GREATER LONDON, UNITED KINGDOM, March 27, 2026 /EINPresswire.com/ -- [The metal-oxide-semiconductor \(MOS\) memory market](#) has witnessed substantial expansion in recent years, driven by the increasing integration of advanced technology in everyday electronics. As demand for faster, more efficient memory solutions grows, this market is set to experience continued robust growth. Let's explore the current market size, the main factors fueling its rise, key regional insights, and emerging trends shaping its future.

Rapid Growth and Market Size of the Metal-Oxide-Semiconductor Memory Market

The size of the metal-oxide-semiconductor (MOS) memory market has surged significantly, with projections indicating an increase from \$57.87 billion in 2025 to \$63.97 billion in 2026, representing a compound annual growth rate (CAGR) of 10.5%. This upward trend during the historical period is largely due to the expanding use of personal computers and servers, the rising demand for consumer electronics, the global growth of data centers, advances in semiconductor manufacturing technology, and the widespread adoption of smartphones and mobile devices.

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Looking ahead, the MOS memory market is expected to maintain its momentum, reaching an estimated \$96.36 billion by 2030, with a CAGR of 10.8%. This anticipated rise is driven by factors such as the increasing deployment of artificial intelligence workloads and high-performance computing, a growing need for edge computing memory solutions, the expansion of 5G networks and connected devices, enhanced use of automotive electronics including electric vehicles, and a focus on energy-efficient memory architectures. Prominent trends influencing the market include higher demand for high-density 3D flash memory, adoption of advanced wafers under 10 nm nodes, greater integration of embedded memory within system-on-chips (SoCs), continued development of DDR5 and next-generation DRAM modules, and an emphasis on low-power, high-speed MOS memory products.

Understanding Metal-Oxide-Semiconductor Memory Technology

Metal-oxide-semiconductor (MOS) memory utilizes a metal-oxide-semiconductor structure to store electrical charges that represent binary information. This type of semiconductor memory is favored for its rapid access speeds, high storage density, and versatility in retaining data in both volatile forms such as RAM and non-volatile types like flash memory. Its widespread use in computers and electronic devices underscores its critical role in modern digital infrastructure.

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How Smartphone Adoption Fuels Metal-Oxide-Semiconductor Memory Market Expansion

One of the primary factors boosting the MOS memory market is the increasing adoption of smartphones. These devices combine traditional telephony functions with powerful computing capabilities, internet connectivity, and a variety of applications for communication, entertainment, and productivity. The growth in smartphone ownership is supported by advancements in mobile internet infrastructure, which provides faster, more dependable, and more widely accessible connections that accommodate data-heavy applications and services.

MOS-based memory technologies, including NAND flash and DRAM, play an essential role in smartphones by enabling rapid data storage and retrieval. This supports smooth app performance, quick boot times, and efficient multitasking. For example, in March 2024, Consumer Affairs reported that smartphone ownership in the United States rose to 92% in 2023 from 86% in 2022. This surge in smartphone penetration clearly contributes to the expanding demand for MOS memory solutions.

Key Regional Dominance and [Growth in the Metal-Oxide-Semiconductor Memory Market](#)

In 2025, Asia-Pacific emerged as the largest market for metal-oxide-semiconductor memory and is projected to be the fastest-growing region during the forecast period. The market report covers various regions including Asia-Pacific, South East Asia, Western Europe, Eastern Europe, North America, South America, the Middle East, and Africa, providing a comprehensive view of global market dynamics. Asia-Pacific's leading position reflects the region's rapid industrialization, technological advancements, and increasing consumer electronics consumption, all driving growth in MOS memory demand.

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